

# TacBond 1.5

## Thermoplastic bonding film

TacBond 1.5 bonding film offers several unique features that make it ideal as a bonding agent for producing laminated strip line and multilayer packages using AGC laminates.

The closely controlled melt point provides a predictable laminating cycle. In addition, the electrical properties of the package are nearly unaffected by the presence of the bonding film. Process chemistries will not affect circuit integrity due to the chemical stability of the bonding film.

### Benefits

- Low Dk
- Low Df
- Chemically Stable
- Closely Controlled Melt Point

### Applications

- Microwave Radios
- High Speed Digital Work Stations
- Satellite Antenna Systems
- Passive Components
- High Layer Count MLBs
- High Speed Chip Test MLBs



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TacBond 1.5 Typical Properties							
Property	Units	Value	Test Method	Property	Units	Value	Test Method
Thickness	mils, mm	1.5, 38		Surface Resistivity	Mohm	10 <sup>10</sup>	ASTM D257
Dk @ 10 GHz		2.35	ASTM D3380	Crystalline Melt Point		373° F/190° C	ASTM D4591
Df @ 10 GHz		0.0025	ASTM D3380	Water Absorption	%	0.005	ASTM D570
Dielectric Strength	v/mil	3,000	ASTM D149	Thermal Conductivity	W/m/k	0.22	
Volume Resistivity	Mohm/cm	10 <sup>12</sup>	ASTM D257	Tensile Strength MD, CD	psi	9,500, 6,000	ASTM D882
				Elongation MD, CD	%	125, 225	ASTM D882

Remark : All reported values are typical and should not be used for specification purposes. In all instances, the user shall determine suitability in any given application.

## Laminating Procedure/Surface Preparation & Handling

1. After copper etching to form circuit traces, it is important to minimize handling of the PTFE surfaces. Cotton gloves should be worn by operators and protective slip sheets placed over each surface for transport to the next process.
2. The PTFE surface from which ED foil has been etched has a sufficient roughness for bonding. Where rolled foil has been etched or unclad laminate is to be bonded to, it is recommended that the PTFE surface be treated to provide adequate adhesion. The same chemistries which are used for PTH preparation are also recommended for surface treating. Plasma etching or the use of sodium based chemistries (such as FluroEtch® by Acton, TetraEtch® by Gore, and Bond-Prep® by APC) are recommended. The specific processing techniques are provided by the supplier.
3. Copper surfaces should be treated for optimum bond strength. A brown oxide treatment - or a treatment of so-called alternative bonders - of the copper circuitry will enhance the surface topography for mechanical bonding with the TacBond adhesive film. The first process step requires a cleaner to remove resist residues and handling oils. A copper micro-etch follows to provide a uni- form roughened surface area. The brown oxide creates needle like crystals which anchor to the bond layer during lamination. As with any chemical process, adequate rinsing is essential after each process step. Salt residues will inhibit bonding. The final rinse should be monitored and maintained at a pH less than 8.5. The layers should be dried and handled without imparting surface contamination such as hand oils.

## Lay-up and Lamination

Recommended bonding temperature: 425° F (220° C)

1. Bake the layers for one hour at 250° F (100° C) to remove moisture. Store the layers in a controlled environment and use within 24 hours.
2. Press pads should be used between the tooling plate and first separator plate to distribute the pressure evenly across the panel. High pressure areas which exist in the plates and circuits to be filled are absorbed by the pads. The pads also provide temperature uniformity from outside to center of the stack. This results in panel to panel thickness consistency.
3. The board should be constructed with TacBond film as supplied. Take care when handling the film during cutting and lay-up to prevent contamination. Depending on the circuit design and filling requirements, one to three sheets of bonding film may be required. The area to be filled and the dielectric requirement should be used to calculate the number of .0015" (38 micron) film sheets needed. Clean, polished steel or aluminum separator plates are recommended to be used between the boards in multiple stack heights.
4. For vacuum assist lamination, pull vacuum for 20 minutes prior to heat up. Maintain vacuum throughout the cycle. The evacuation of air from the stack will aid in assuring complete encapsulation of circuits.
5. A thermocouple placed in the outside border area of the center board in the stack will allow for temperature monitoring and determination of adequate cycle time.
6. This stack may be loaded into a hot or cold press to start. The heat rise and cycle profiles will differ if not compensated for with press pad lagging. The heat input into the package is not critical however it should be controlled to minimize the differential between the outside and center of the stack. Typically, the heat rate is between 12 – 20° F/min (6 - 9° C/min) from ambient to 425° F (220° C).
7. Pressure can be applied immediately upon loading into the press. The pressure will vary with panel size and should be used within the range of 100 - 200 psi (7 – 14 bar).
8. Maintain the stack at 425° F (220° C) for 15 minutes. The temperature should not exceed 450° F (230° C).
9. Cool down under pressure in the lamination press or transfer to a cool down press. If transferred, minimize the time that the stack does not have pressure. Maintain under pressure until the stack is below 200° F (100° C).